74ALVT16373 16-bit transparent D-type latch; 3-state Rev. 4 – 2 February 2018

**Product data sheet** 

#### **General description** 1

The 74ALVT16373 is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 2.5 V or 3.3 V with I/O compatibility up to 5 V.

This device is a 16-bit transparent D-type latch with non-inverting 3-state bus compatible outputs. The device can be used as two 8-bit latches or one 16-bit latch. When latch enable (nLE) input is HIGH, the nQn outputs follow the date (nDn) inputs. When latch enable is taken LOW, the nQn outputs are latched at the levels of the D inputs one setup time prior to the HIGH-to-LOW transition.

#### **Features and benefits** 2

- 16-bit transparent latch
- 5 V I/O compatible
- 3-state buffers
- Output capability: +64 mA/–32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- · Live insertion/extraction permitted
- Power-up reset
- Power-up 3-State
- No bus current loading when output is tied to 5 V bus
- Latch-up protection:
  - JESD 17: exceeds 500 mA
- ESD protection:
  - MIL STD 883 method 3015: exceeds 2000 V
  - MM exceeds 200 V

#### **Ordering information** 3

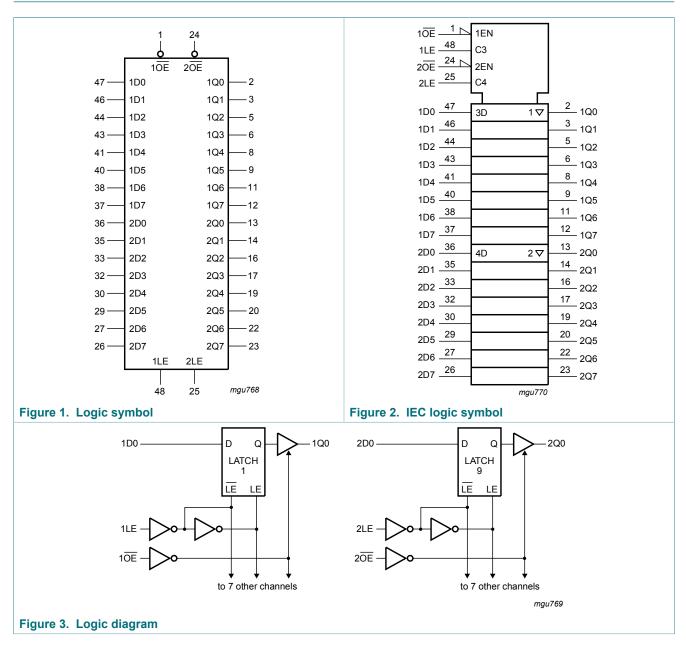
#### Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74ALVT16373DL	-40 °C to +85 °C	SSOP48	plastic shrink small outline package; 48 leads; body width 7.5 mm	SOT370-1				
74ALVT16373DGG	-40 °C to +85 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1				

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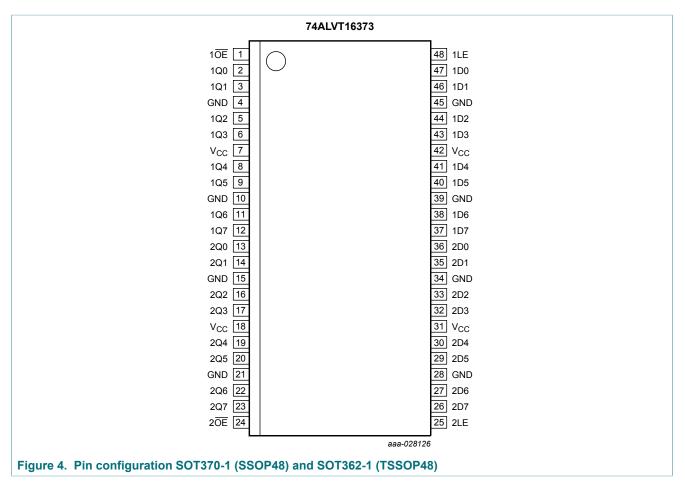
### 4 Functional diagram



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### 5 Pinning information

#### 5.1 Pinning



#### 5.2 Pin description

#### Table 2. Pin description

Symbol	Pin	Description
1D0, 1D1, 1D2, 1D3, 1D4, 1D5, 1D6, 1D7	47, 46, 44, 43, 41, 40, 38, 37	data inputs
2D0, 2D1, 2D2, 2D3, 2D4, 2D5, 2D6, 2D7	36, 35, 33, 32, 30, 29, 27, 26	data inputs
1Q0, 1Q1, 1Q2, 1Q3, 1Q4, 1Q5, 1Q6, 1Q7	2, 3, 5, 6, 8, 9, 11, 12	data outputs
2Q0, 2Q1, 2Q2, 2Q3, 2Q4, 2Q5, 2Q6, 2Q7	13, 14, 16, 17, 19, 20, 22, 23	data outputs
10E, 20E	1, 24	output enable inputs (active LOW)
1LE, 2LE	48, 25	latch enable inputs (active HIGH)
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
V <sub>CC</sub>	7, 18, 31, 42	supply voltage

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### 6 Functional description

#### Table 3. Function table <sup>[1]</sup>

Operating mode	Inputs			Internal	Outputs
	nOE	nLE	nDn	latches	nQn
enable and read register (transparent mode)	L	Н	L	L	
	L	Н	Н	Н	Н
latch and read register	L	$\downarrow$	I	L	nQn L H L L H NC Z
	L	Ļ	h	Н	
Hold	L	L	Х	NC	NC
Latch register and disable outputs	Н	L	Х	NC	Z
	Н	Н	nDn	nDn	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

 $\downarrow$  = HIGH-to-LOW LE transition;

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;

I = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;

X = don't care;

NC = No change;

Z = high-impedance OFF-state.

### 7 Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
VI	input voltage		[1]	-0.5	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state	[1]	-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
I <sub>O</sub>	output current	output in LOW-state		-	128	mA
		output in HIGH-state		-64	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
Tj	junction temperature		[2]	-	+150	°C

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

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### 8 Recommended operating conditions

Table 5.	Recommended	operating	conditions
		oporating	oonantiono

Symbol	Parameter	Conditions	V <sub>CC</sub> = 2.5 \	$V_{CC}$ = 2.5 V ± 0.2 V		$V_{CC}$ = 3.3 V ± 0.3 V	
			Min	Max	Min	Max	
V <sub>CC</sub>	supply voltage		2.3	2.7	3.0	3.6	V
VI	input voltage		0	5.5	0	5.5	V
I <sub>OH</sub>	HIGH-level output current		-	-8	-	-32	mA
I <sub>OL</sub>	LOW-level output current	none	-	8	-	32	mA
		current duty cycle $\leq$ 50 %; f <sub>i</sub> $\geq$ 1 kHz	-	24	-	64	mA
Δt/ΔV	input transition rise and fall rate	outputs enabled	-	10	-	10	ns/V
T <sub>amb</sub>	ambient temperature	free-air	-40	+85	-40	+85	°C

## 9 Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions;  $T_{amb} = -40$  °C to +85 °C; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Typ <sup>[1]</sup>	Max	Unit
V <sub>CC</sub> = 2.5	V ± 0.2 V			I			
V <sub>IK</sub>	input clamping voltage	V <sub>CC</sub> = 2.3 V; I <sub>IK</sub> = -18 mA		-	-0.85	-1.2	V
V <sub>IH</sub>	HIGH-level input voltage			1.7	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	0.7	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{CC}$ = 2.3 V to 2.7 V; I <sub>O</sub> = -100 µA		V <sub>CC</sub> - 0.2	-	-	V
		V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = -8 mA		1.8	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = 100 μA		-	0.07	0.2	V
		V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = 24 mA		-	0.3	0.5	V
V <sub>OL(pu)</sub>	power-up LOW-level output voltage	V <sub>CC</sub> = 2.7 V; I <sub>O</sub> = 1 mA; V <sub>I</sub> = V <sub>CC</sub> or GND	[2]	-	-	0.55	V
I <sub>I</sub>	input leakage current	all input pins	[3]				
		$V_{CC}$ = 0 V or 2.7 V; V <sub>I</sub> = 5.5 V		-	0.1	10	μA
		control pins				- ν 0.2 ν 0.5 ν 0.55 ν 10 μ ±1 μ -5 μ ±100 μ	
		$V_{CC}$ = 2.7 V; $V_{I}$ = $V_{CC}$ or GND		-	0.1	±1	μA
		data pins;	[3]				
		$V_{CC}$ = 2.7 V; $V_{I}$ = $V_{CC}$		-	0.1	1	μA
		V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = 0 V		-	0.1	-5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC}$ = 0 V; V <sub>1</sub> or V <sub>0</sub> = 0 V to 4.5 V		-	0.1	±100	μA
I <sub>BHL</sub>	bus hold LOW current	data inputs; $V_{CC}$ = 2.3 V; $V_{I}$ = 0.7 V	[4]	-	90	-	μA
I <sub>BHH</sub>	bus hold HIGH current	data inputs; $V_{CC}$ = 2.3 V; $V_{I}$ = 1.7 V	[4]	-	-10	-	μA
I <sub>EX</sub>	external current	output in HIGH-state when $V_O > V_{CC}$ ; $V_O = 5.5 V$ ; $V_{CC} = 2.3 V$		-	10	125	μA

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### 16-bit transparent D-type latch; 3-state

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
I <sub>O(pu/pd)</sub>	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; \text{ nOE} = \text{don't care}$ <sup>[5]</sup>	-	1	100	μA
l <sub>oz</sub>	OFF-state output current	$V_{CC}$ = 2.7 V; $V_{I}$ = $V_{IL}$ or $V_{IH}$				
		output HIGH: V <sub>O</sub> = 2.3V	-	0.5	5	μA
		output LOW: V <sub>O</sub> = 0.5 V	-	0.5	-5	μA
I <sub>CC</sub>	supply current	$V_{CC}$ = 2.7 V; $V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A				
		outputs HIGH	-	0.04	0.1	mA
		outputs LOW	-	2.3	4.5	mA
		outputs disabled [6]	-	0.04	0.1	mA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_{CC}$ = 2.3 V to 2.7 V; <sup>[7]</sup> one input at $V_{CC}$ - 0.6 V; other inputs at $V_{CC}$ or GND	-	0.04	0.4	mA
CI	input capacitance	V <sub>I</sub> = 0 V or V <sub>CC</sub>	-	3	-	pF
Co	output capacitance	Outputs disabled; $V_0 = 0 V \text{ or } 3 V$	-	9	-	pF
V <sub>CC</sub> = 3.3	V ± 0.3 V					
V <sub>IK</sub>	input clamping voltage	V <sub>CC</sub> = 3.0 V; I <sub>IK</sub> = -18 mA	-	-0.85	-1.2	V
V <sub>IH</sub>	HIGH-level input voltage		2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage		-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{CC}$ = 3.3 V ± 0.3 V; I <sub>O</sub> = -100 µA	V <sub>CC</sub> - 0.2	V <sub>CC</sub>	-	V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = -32 mA	2.0	2.3	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 100 μA	-	0.07	0.2	V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 16 mA	-	0.25	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 32 mA	-	0.3		V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 64 mA	-	0.4	0.55	V
V <sub>OL(pu)</sub>	power-up LOW-level output voltage	$V_{CC}$ = 3.6 V; I <sub>O</sub> = 1 mA; V <sub>I</sub> = V <sub>CC</sub> or GND [2]	-	-	0.55	V
I	input leakage current	all input pins [3]				
		$V_{CC} = 0 V \text{ or } 3.6 V; V_1 = 5.5 V$	-	0.1	10	μA
		control pins				
		$V_{CC}$ = 3.6 V; $V_{I}$ = $V_{CC}$ or GND	-	0.1	±1	μA
		data pins [3]				
		$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = V_{CC}$	-	0.5	1	μA
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V	-	0.1	-5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC}$ = 0 V; V <sub>I</sub> or V <sub>O</sub> = 0 V to 4.5 V	-	0.1	±100	μA
I <sub>BHL</sub>	bus hold LOW current	data inputs; $V_{CC}$ = 3 V; $V_{I}$ = 0.8 V	75	130	-	μA
I <sub>BHH</sub>	bus hold HIGH current	data inputs; $V_{CC}$ = 3 V; $V_{I}$ = 2.0 V	-75	-140	-	μA
I <sub>BHLO</sub>	bus hold LOW overdrive current	data inputs; $V_{CC}$ = 3.6 V; V <sub>1</sub> = 0 V to 3.6 V	500	-	-	μA
І <sub>внно</sub>	bus hold HIGH overdrive current	data inputs; $V_{CC}$ = 3.6 V; V <sub>I</sub> = 0 V to 3.6 V	-500	-	-	μA

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#### 16-bit transparent D-type latch; 3-state

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
I <sub>EX</sub>	external current	output in HIGH-state when V <sub>O</sub> > V <sub>CC</sub> ; V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 3.0 V	-	10	125	μA
I <sub>O(pu/pd)</sub>	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; \text{ nOE} = \text{don't care}$ <sup>[9]</sup>	-	1	±100	μA
I <sub>OZ</sub>	OFF-state output current	$V_{CC}$ = 3.6 V; $V_{I}$ = $V_{IL}$ or $V_{IH}$				
		output HIGH: V <sub>O</sub> = 3.0V	-	0.5	125	μA
		output LOW: $V_0 = 0.5 V$	-	0.5	-5	μA
I <sub>CC</sub>	supply current	$V_{CC}$ = 3.6 V; $V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A				
		outputs HIGH	-	0.04	125 ±100 5 -5 0.1 5 0.1	mA
		outputs LOW	-	3.5	5	mA
		outputs disabled [6]	-	0.05	0.1	mA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_{CC}$ = 3 V to 3.6 V; <sup>[7]</sup> one input at $V_{CC}$ - 0.6 V; other inputs at $V_{CC}$ or GND	-	0.04	0.4	mA
CI	input capacitance	$V_{I} = 0 V \text{ or } V_{CC}$	-	3	-	pF
Co	output capacitance	output disabled; $V_0 = 0 V \text{ or } 3 V$	-	9	-	pF

[1] All typical values for V<sub>CC</sub> = 2.5 V  $\pm$  0.2 V are measured at V<sub>CC</sub> = 2.5 V and T<sub>amb</sub> = 25 °C.

All typical values for V<sub>CC</sub> = 3.3 V ± 0.3 V are measured at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C. For valid test results, data must not be loaded into the latches after applying power.

[2]

[3] Unused pins at  $V_{CC}$  or GND. [4] Not guaranteed.

[5] This parameter is valid for any V<sub>CC</sub> between 0 V and 1.2 V with a transition time of up to 10 ms.

From  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 2.5 V ± 0.2 V a transition time of 100 µs is permitted. This parameter is valid for  $T_{amb}$  = 25 °C only. [6]  $I_{CC}$  with outputs disabled is measured with outputs pulled to  $V_{CC}$  or GND.

[7] This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.

[8] This is the bus hold overdrive current required to force the input to the opposite logic state.

[9] This parameter is valid for any V<sub>CC</sub> between 0 V and 1.2 V with a transition time of up to 10 ms.

From  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 3.3 V ± 0.3 V a transition time of 100 µs is permitted. This parameter is valid for  $T_{amb}$  = 25 °C only.

### **10** Dynamic characteristics

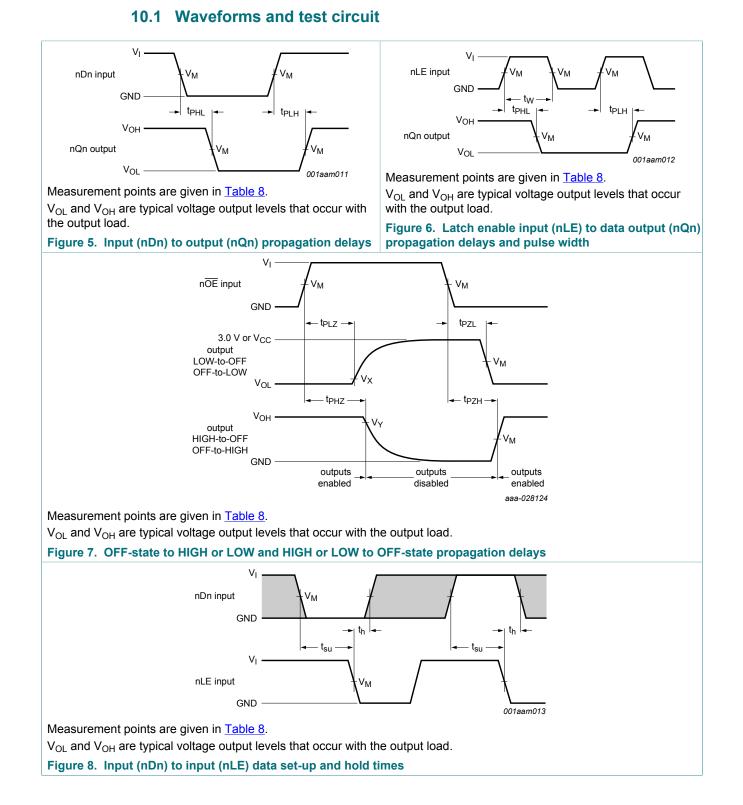
#### Table 7. Dynamic characteristics

At recommended operating conditions;  $T_{amb} = -40$  °C to +85 °C; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9.

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
V <sub>CC</sub> = 2	.5 V ± 0.2 V				<u> </u>	
t <sub>PLH</sub>	LOW to HIGH propagation delay	nDn to nQn; see <u>Figure 5</u>	1.0	2.0	3.2	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	nDn to nQn; see <u>Figure 5</u>	1.0	2.4	4.2	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	nLE to nQn; see Figure 6	1.5	2.6	4.2	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	nLE to nQn; see Figure 6	1.5	2.8	4.5	ns
t <sub>PZH</sub>	OFF-state to HIGH propagation delay	nOE to nQn; see Figure 7	2.0	3.5	5.5	ns
t <sub>PZL</sub>	OFF-state to LOW propagation delay	nOE to nQn; see Figure 7	1.5	2.6	4.7	ns
t <sub>PHZ</sub>	HIGH to OFF-state propagation delay	nOE to nQn; see Figure 7	1.5	2.7	4.5	ns
t <sub>PLZ</sub>	LOW to OFF-state propagation delay	nOE to nQn; see Figure 7	1.0	2.0	3.5	ns
t <sub>su(H)</sub>	set-up time HIGH	nDn to nLE; see Figure 8	0	-0.7	-	ns
t <sub>su(L)</sub>	set-up time LOW	nDn to nLE; see Figure 8	1.5	0.2	-	ns
t <sub>h(H)</sub>	hold time HIGH	nDn to nLE; see Figure 8	0.5	-0.2	-	ns
t <sub>h(L)</sub>	hold time LOW	nDn to nLE; see Figure 8	1.5	0.7	-	ns
t <sub>WH</sub>	pulse width HIGH	nLE; see <u>Figure 6</u>	1.5	-	-	ns
V <sub>CC</sub> = 3	.3 V ± 0.3 V					
t <sub>PLH</sub>	LOW to HIGH propagation delay	nDn to nQn; see Figure 5	0.5	1.6	2.5	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	nDn to nQn; see Figure 5	0.5	1.8	2.9	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	nLE to nQn; see Figure 6	1.0	2.0	3.1	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	nLE to nQn; see Figure 6	1.0	2.3	3.3	ns
t <sub>PZH</sub>	OFF-state to HIGH propagation delay	nOE to nQn; see Figure 7	1.5	2.3	4.0	ns
t <sub>PZL</sub>	OFF-state to LOW propagation delay	nOE to nQn; see Figure 7	1.0	1.9	3.1	ns
t <sub>PHZ</sub>	HIGH to OFF-state propagation delay	nOE to nQn; see Figure 7	1.5	2.9	4.5	ns
t <sub>PLZ</sub>	LOW to OFF-state propagation delay	nOE to nQn; see Figure 7	1.5	2.3	3.7	ns
t <sub>su(H)</sub>	set-up time HIGH	nDn to nLE; see Figure 8	0.5	-0.2	-	ns
t <sub>su(L)</sub>	set-up time LOW	nDn to nLE; see Figure 8	0.8	0.2	-	ns
t <sub>h(H)</sub>	hold time HIGH	nDn to nLE; see Figure 8	0.8	0	-	ns
t <sub>h(L)</sub>	hold time LOW	nDn to nLE; see Figure 8	1.0	0.2	-	ns
t <sub>WH</sub>	pulse width HIGH	nLE; see <u>Figure 6</u>	1.5	-	-	ns

[1] All typical values for V<sub>CC</sub> = 2.5 V ± 0.2 V are measured at V<sub>CC</sub> = 2.5 V and T<sub>amb</sub> = 25 °C. All typical values for V<sub>CC</sub> = 3.3 V ± 0.3 V are measured at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.

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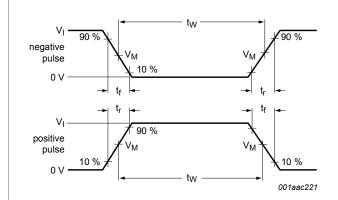


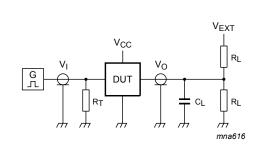
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V <sub>cc</sub>	Input		Output			
	VI	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>	
$V_{CC} \le 2.7 V$	V <sub>CC</sub>	0.5 x V <sub>CC</sub>	0.5 x V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V	
V <sub>CC</sub> ≥ 3.0 V	3.0 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V	







Test data is given in Table 9.

Definitions test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

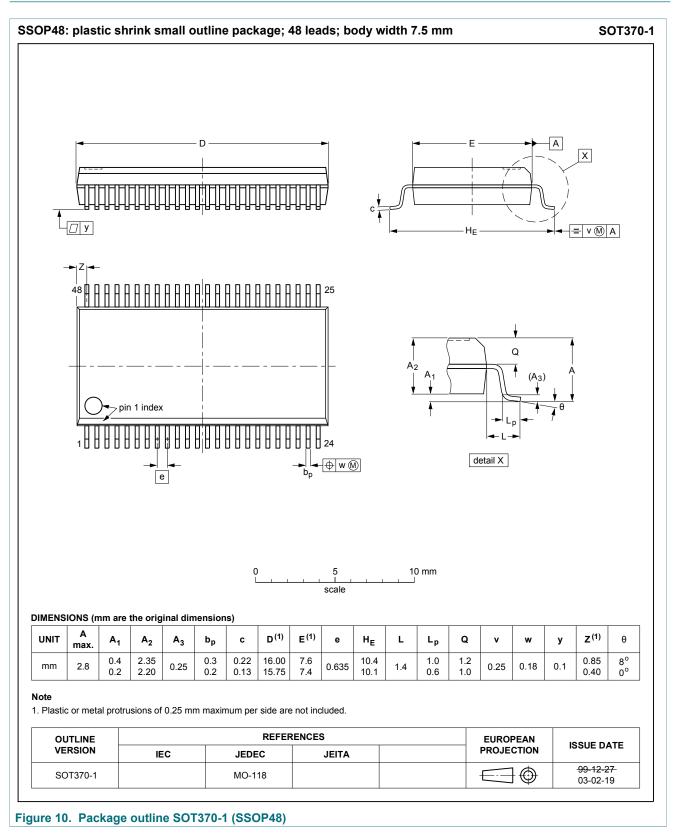
V<sub>EXT</sub> = Test voltage for switching times.

Figure 9. Test circuit for measuring switching times

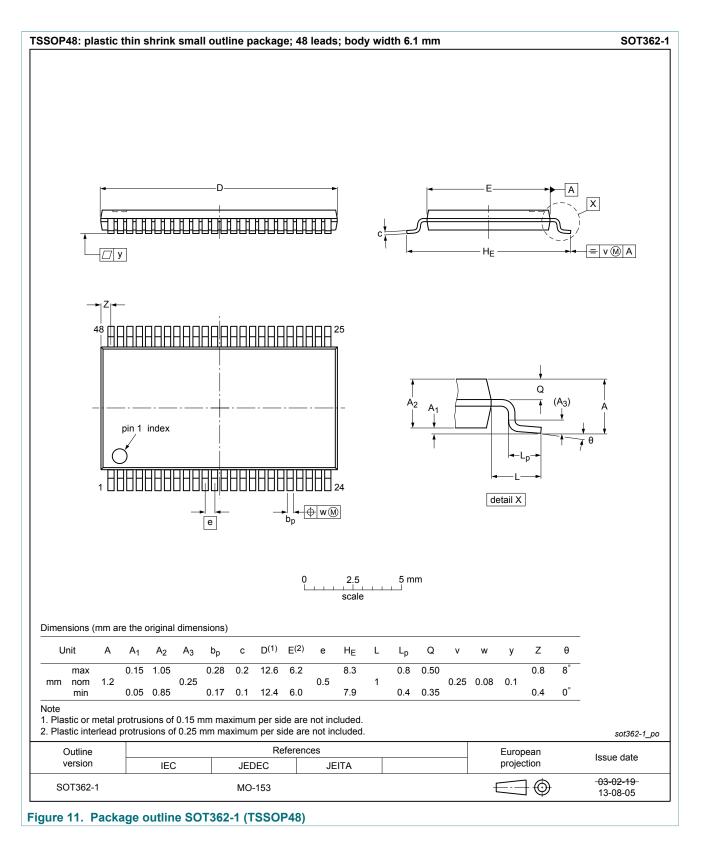
Input			Load		V <sub>EXT</sub>			
VI	f <sub>i</sub>	tw	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHZ</sub> , t <sub>PZH</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>
3.0 V or $V_{CC}$ whichever is less	≤ 10 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	GND	6 V or $V_{CC}$ x 2	open

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# 11 Package outline



#### 16-bit transparent D-type latch; 3-state



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### **12 Abbreviations**

Table 10. Abbreviations				
Acronym	Description			
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
MIL	Military			
ММ	Machine Model			
TTL	Transistor-Transistor Logic			

# **13 Revision history**

Table 11. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
74ALVT16373 v.4	20180202	Product data sheet	-	74ALVT16373 v.3	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
74ALVT16373 v.3	19991018	Product specification	-	74ALVT16373 v.2	
74ALVT16373 v.2	19980213	Product specification	-	74ALVT16373 v.1	
74ALVT16373 v.1	19960529	Product specification	-	-	

### 14 Legal information

#### 14.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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#### 16-bit transparent D-type latch; 3-state

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# 74ALVT16373

#### 16-bit transparent D-type latch; 3-state

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